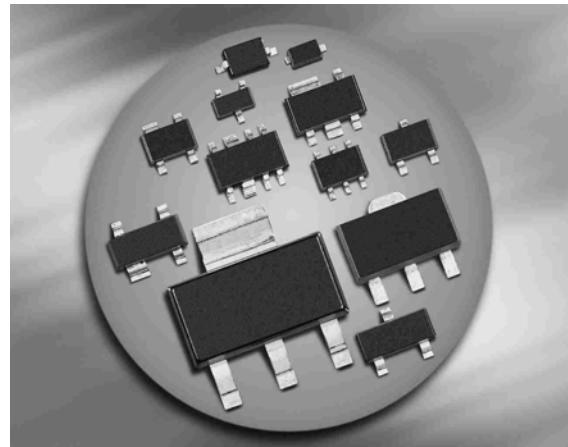


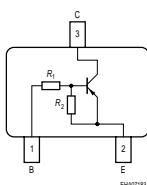
PNP Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1 = 4.7\text{k}\Omega$, $R_2 = 10\text{k}\Omega$)



BCR164F/L3

BCR164T



| Type | Marking | Pin Configuration | | | | | | Package |
|-----------|---------|-------------------|-----|-----|---|---|---|----------|
| BCR164F* | U6s | 1=B | 2=E | 3=C | - | - | - | TSFP-3 |
| BCR164L3* | U6 | 1=B | 2=E | 3=C | - | - | - | TSLP-3-4 |
| BCR164T* | U6s | 1=B | 2=E | 3=C | - | - | - | SC75 |

* Preliminary

Maximum Ratings

| Parameter | Symbol | Value | Unit |
|--|-------------|-------------------|------|
| Collector-emitter voltage | V_{CEO} | 50 | V |
| Collector-base voltage | V_{CBO} | 50 | |
| Emitter-base voltage | V_{EBO} | 5 | |
| Input on voltage | $V_{i(on)}$ | 15 | |
| Collector current | I_C | 100 | mA |
| Total power dissipation- BCR164F, $T_S \leq 128^\circ\text{C}$ BCR164L3, $T_S \leq 135^\circ\text{C}$ BCR164T, $T_S \leq 109^\circ\text{C}$ | P_{tot} | 250 250 250 | mW |
| Junction temperature | T_j | 150 | °C |
| Storage temperature | T_{Stg} | -65 ... 150 | |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|--|-------------------|--------------------------------------|------|
| Junction - soldering point ¹⁾ BCR164F BCR164L3 BCR164T | R_{thJS} | ≤ 90 ≤ 60 ≤ 165 | - |
| | | | |
| | | | |

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|-----------|--------|--------|------|------|------|
| | | min. | typ. | max. | |

DC Characteristics

| | | | | | |
|---|-----------------------------|------|------|------|---------------|
| Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$ | $V_{(\text{BR})\text{CEO}}$ | 50 | - | - | V |
| Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$ | $V_{(\text{BR})\text{CBO}}$ | 50 | - | - | |
| Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$ | I_{CBO} | - | - | 100 | nA |
| Emitter-base cutoff current $V_{EB} = 10 \text{ V}, I_C = 0$ | I_{EBO} | - | - | 520 | μA |
| DC current gain ²⁾ $I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$ | h_{FE} | 30 | - | - | - |
| Collector-emitter saturation voltage ²⁾ $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ | V_{CEsat} | - | - | 0.3 | V |
| Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$ | $V_{i(\text{off})}$ | 0.5 | - | 1.1 | |
| Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0.3 \text{ V}$ | $V_{i(\text{on})}$ | 0.5 | - | 1.4 | |
| Input resistor | R_1 | 3.2 | 4.7 | 6.2 | k Ω |
| Resistor ratio | R_1/R_2 | 0.42 | 0.47 | 0.52 | - |

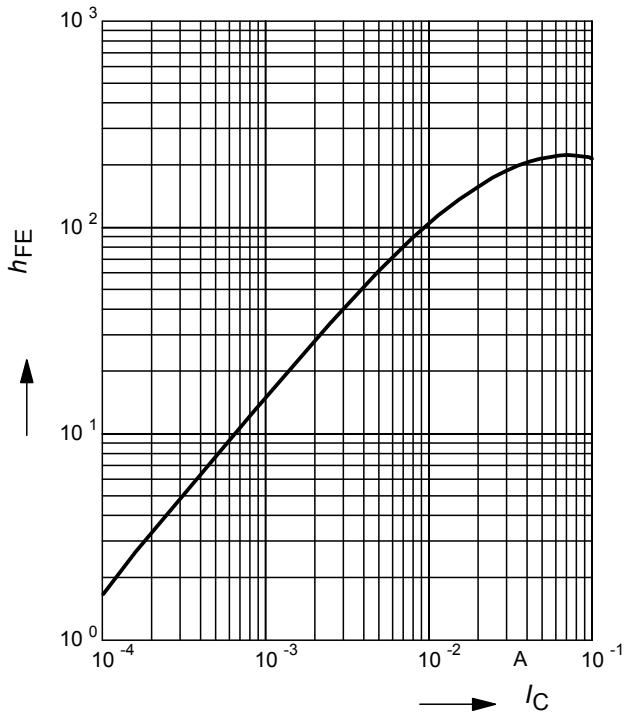
AC Characteristics

| | | | | | |
|--|----------|---|-----|---|-----|
| Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$ | f_T | - | 160 | - | MHz |
| Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$ | C_{cb} | - | 3 | - | pF |

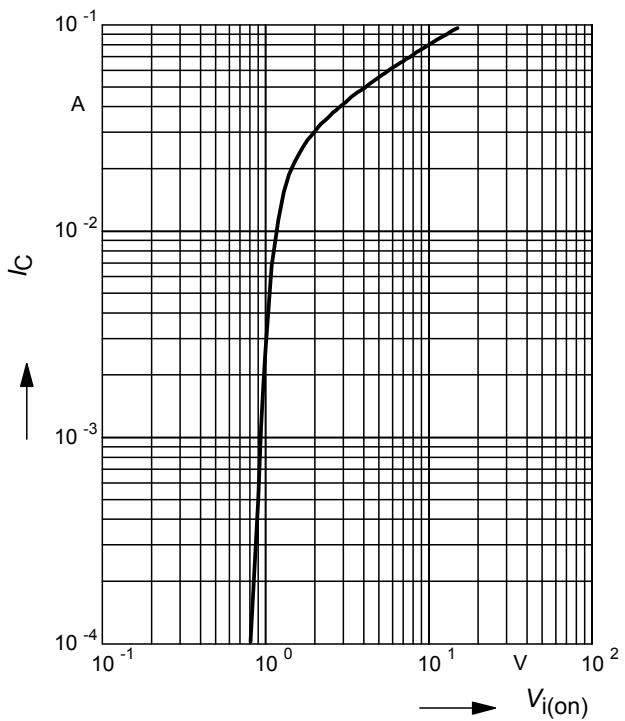
¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

²⁾Pulse test: $t < 300 \mu\text{s}$; $D < 2\%$

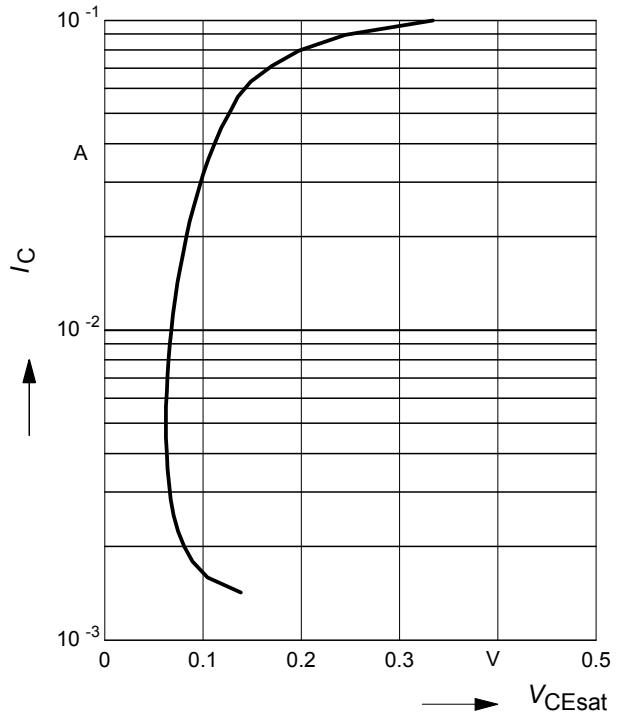
DC current gain $h_{FE} = f(I_C)$
 $V_{CE} = 5 \text{ V}$ (common emitter configuration)



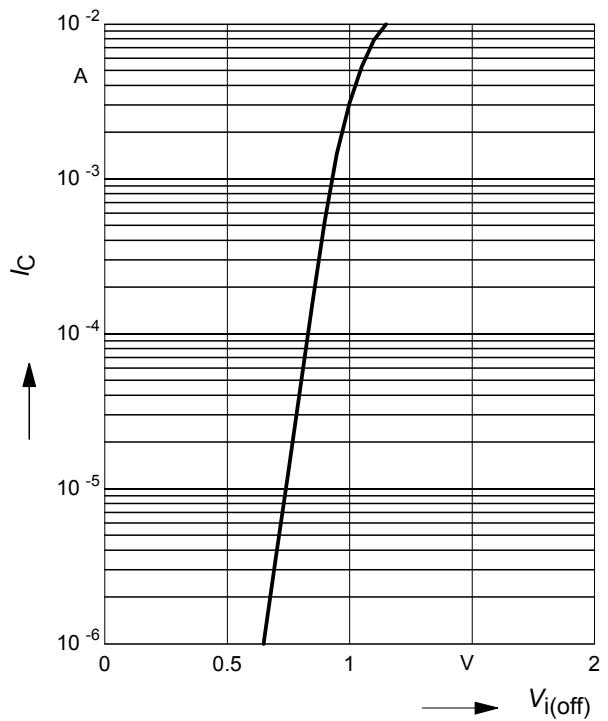
Input on Voltage $V_{i(on)} = f(I_C)$
 $V_{CE} = 0.3 \text{ V}$ (common emitter configuration)



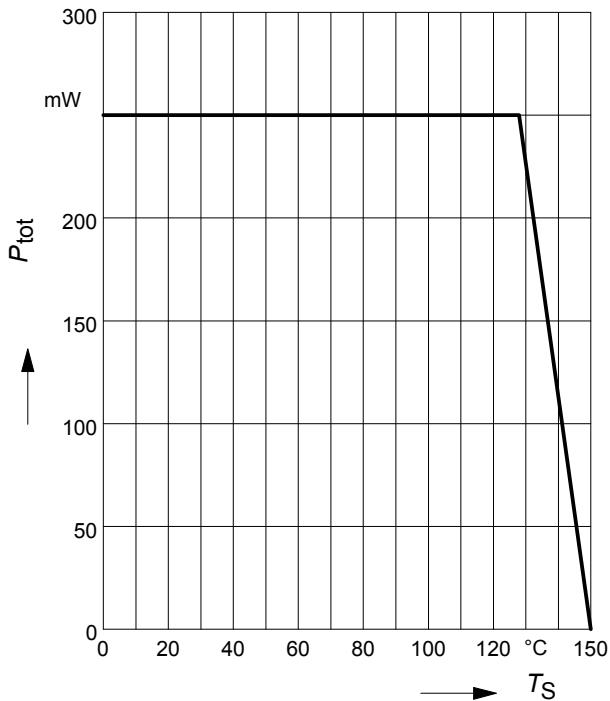
Collector-emitter saturation voltage
 $V_{CEsat} = f(I_C)$, $h_{FE} = 20$



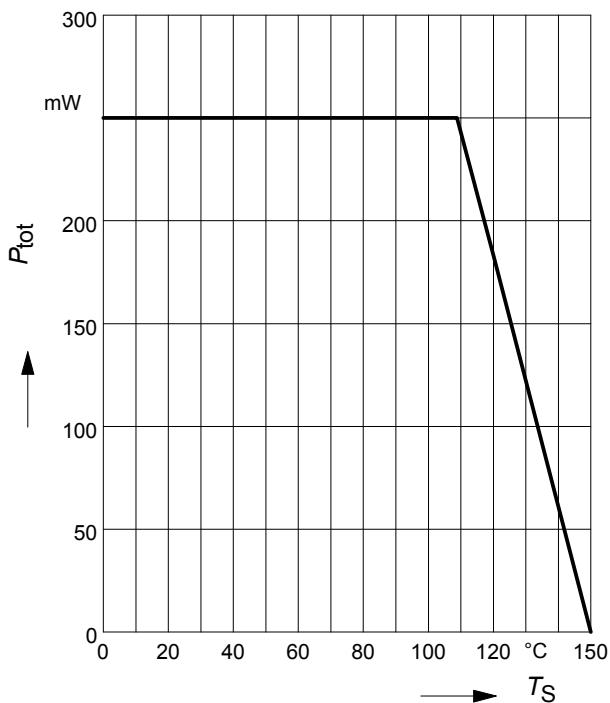
Input off voltage $V_{i(off)} = f(I_C)$
 $V_{CE} = 5 \text{ V}$ (common emitter configuration)



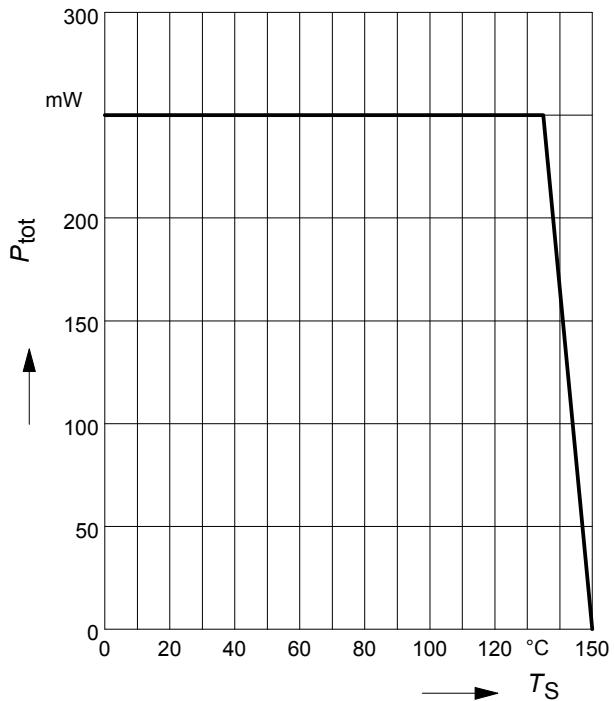
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR164F



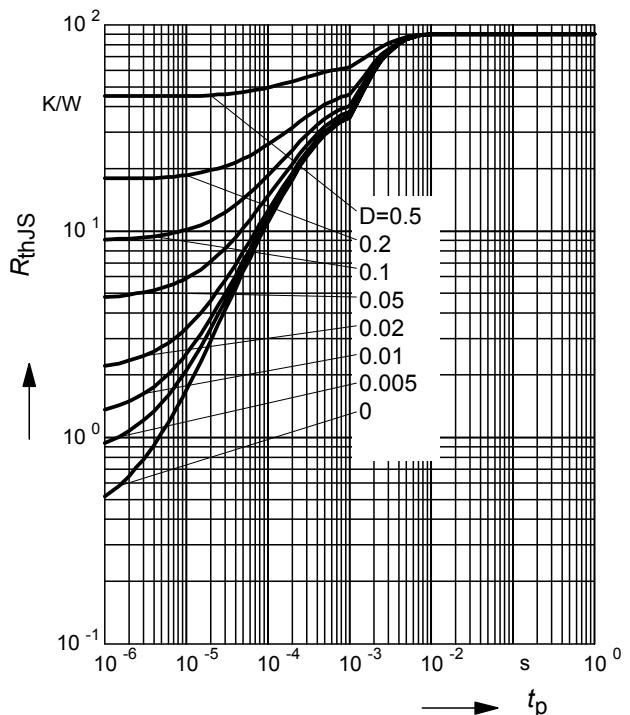
Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR164T



Total power dissipation $P_{\text{tot}} = f(T_S)$
BCR164L3



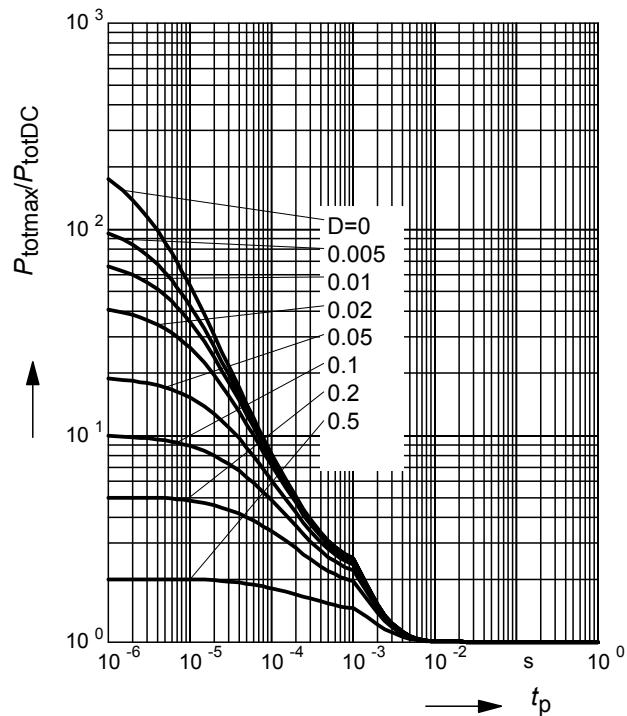
Permissible Puls Load $R_{\text{thJS}} = f(t_p)$
BCR164F



Permissible Pulse Load

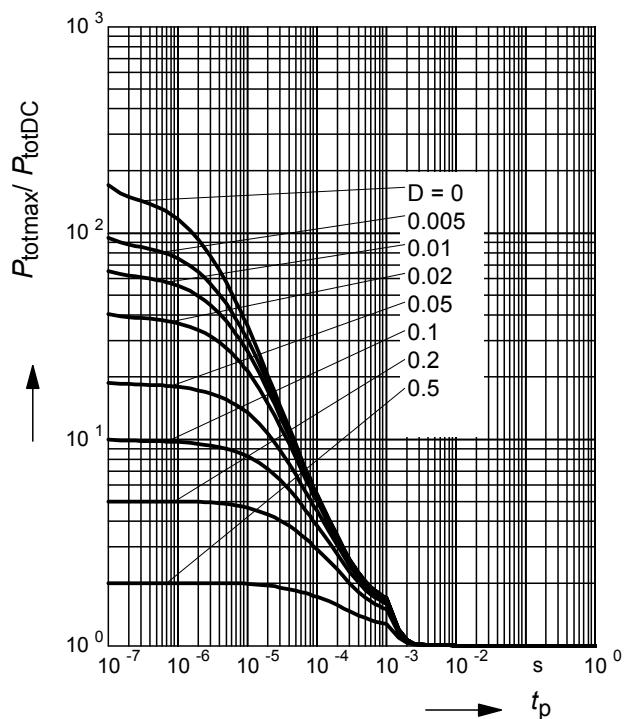
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR164F

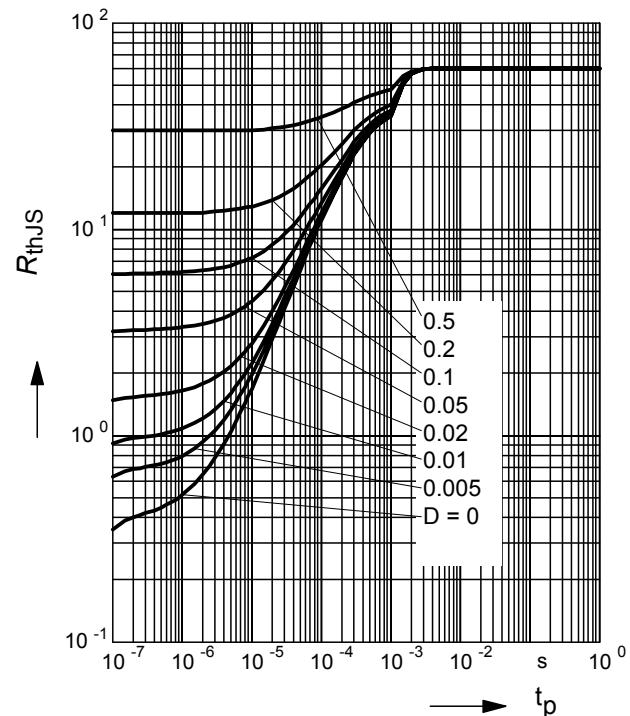

Permissible Pulse Load

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

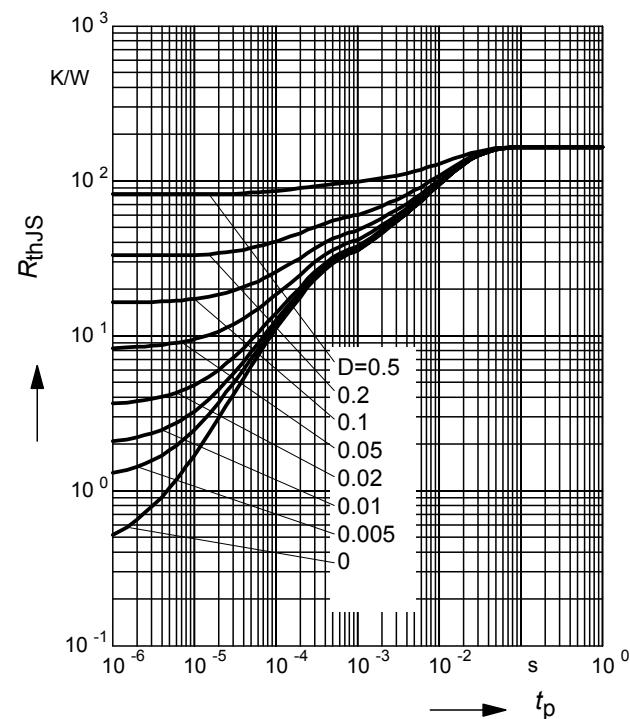
BCR164L3


Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

BCR164L3


Permissible Puls Load $R_{\text{thJS}} = f(t_p)$

BCR164T



Permissible Pulse Load

$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$$

BCR164T

